



ELECTRONIC COPY

LABORATORY GROWN DIAMOND REPORT

March 23, 2023	
IGI Report Number	LG573390717
Description	LABORATORY GROWN DIAMOND
Shape and Cutting Style	ROUND BRILLIANT
Measurements	6.77 - 6.80 X 4.21 MM

GRADING RESULTS

Carat Weight	1.19 CARAT
Color Grade	E
Clarity Grade	VVS 2
Cut Grade	IDEAL

ADDITIONAL GRADING INFORMATION

Polish	EXCELLENT
Symmetry	EXCELLENT
Fluorescence	NONE
Inscription(s)	 LG573390717

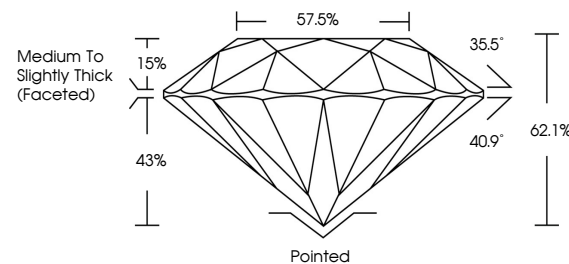
Comments: As Grown - No indication of post-growth treatment.
This Laboratory Grown Diamond was created by High Pressure High Temperature (HPHT) growth process.
Type II

LABORATORY GROWN DIAMOND REPORT

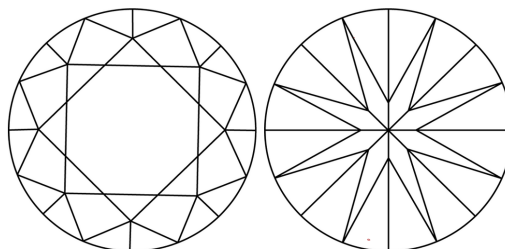
LG573390717

Report verification at igi.org

PROPORTIONS



CLARITY CHARACTERISTICS



KEY TO SYMBOLS

Red symbols indicate internal characteristics.
Green symbols indicate external characteristics.

LABORATORY GROWN
DIAMOND REPORT

GRADING SCALES

CLARITY

IF	VVS ¹⁻²	VS ¹⁻²	SI ¹⁻²	I ¹⁻³
Internally Flawless	Very Very Slightly Included	Very Slightly Included	Slightly Included	Included

COLOR

D E F G H I J Faint Very Light Light



Sample Image Used



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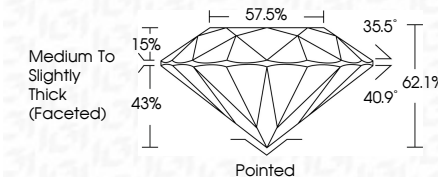
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Inscription(s)	165 LG573390717
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March 23, 2023	1.19 CARAT
Q Report No. G57890717	E
ROUND BRILLIANT	VVS 2
1.00 X 6.50 X 4.21 MM	ID54L
	62.1%
	57.5%
	Medium to Slightly Thick (Faceted)
	Ported
	EXCELLENT
	EXCELLENT
	NONE
	169 L5675390717
Comments:	No indication of post-growth treatment.
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	Type II